

SNAS550B - FEBRUARY 1995 - REVISED APRIL 2013

# LM1877 Dual Audio Power Amplifier

Check for Samples: LM1877

# FEATURES

- 2W/Channel
- -65 dB Ripple Rejection, Output Referred
- -65 dB Channel Separation, Output Referred
- Wide Supply Range, 6V–24V
- Very Low Cross-Over Distortion
- Low Audio Band Noise
- AC Short Circuit Protected
- Internal Thermal Shutdown

# **APPLICATIONS**

- Multi-Channel Audio Systems
- Stereo Phonographs
- Tape Recorders and Players
- AM-FM Radio Receivers
- Servo Amplifiers
- Intercom Systems
- Automotive Products

### **Connection Diagram**

# DESCRIPTION

The LM1877 is a monolithic dual power amplifier designed to deliver 2W/channel continuous into  $8\Omega$  loads. The LM1877 is designed to operate with a low number of external components, and still provide flexibility for use in stereo phonographs, tape recorders and AM-FM stereo receivers. Each power amplifier is biased from a common internal regulator to provide high power supply rejection, and output Q point centering. The LM1877 is internally compensated for all gains greater than 10.

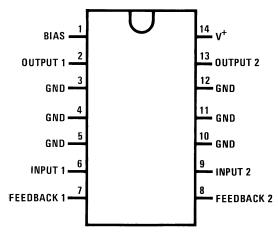


Figure 1. 14-Pin SOIC or PDIP (Top View) See NPA0014B or NFF0014A Package

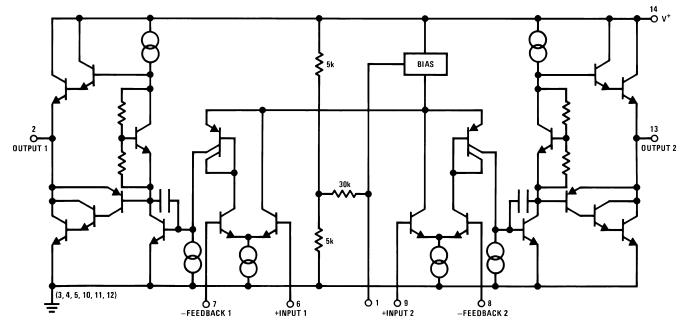
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INSTRUMENTS

EXAS

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#### **Equivalent Schematic Diagram**





These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

# Absolute Maximum Ratings<sup>(1)(2)</sup>

Supply Voltage		26V
Input Voltage		±0.7V
Operating Temperature		0°C to +70°C
Storage Temperature		−65°C to +150°C
Junction Temperature		150°C
Lead Temperature	PDIP Package Soldering (10 sec.)	260°C
	SOIC Package Infrared (15 sec.)	220°C
	SOIC Package Vapor Phase (60 sec.)	215°C
Thermal Resistance	θ <sub>JC</sub> (PDIP Package)	30°C/W
	θ <sub>JA</sub> (PDIP Package)	79°C/W
	θ <sub>JC</sub> (SOIC Package)	27°C/W
	θ <sub>JA</sub> (SOIC Package)	114°C/W

(1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not ensure specific performance limits.

(2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/Distributors for availability and specifications.

### Electrical Characteristics

 $V_{S} = 20V$ ,  $T_{A} = 25^{\circ}C^{(1)}R_{L} = 8\Omega$ ,  $A_{V} = 50$  (34 dB) unless otherwise specified

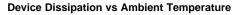
Parameter	Conditions	Min	Тур	Max	Units
Total Supply Current	$P_0 = 0W$		25	50	mA
Output Power	THD = 10%				
LM1877	$V_{S} = 20V, R_{L} = 8\Omega$	2.0			W/Ch
	$V_{S} = 12V, R_{L} = 8\Omega$		1.3		W/Ch
Total Harmonic Distortion	f = 1 kHz, V <sub>S</sub> = 14V				
LM1877	P <sub>O</sub> = 50 mW/Channel		0.075		%
	P <sub>O</sub> = 500 mW/Channel		0.045		%
	P <sub>O</sub> = 1 W/Channel		0.055		%
Output Swing	$R_L = 8\Omega$		V <sub>S</sub> -6		Vp-p
Channel Separation	$C_{F} = 50 \ \mu F, \ C_{IN} = 0.1 \ \mu F,$				
	f = 1 kHz, Output Referred				
	$V_{S} = 20V, V_{O} = 4 Vrms$	-50	-70		dB
	$V_S = 7V, V_O = 0.5 Vrms$		-60		dB
PSRR Power Supply	C <sub>F</sub> = 50 μF, C <sub>IN</sub> = 0.1 μF,				
Rejection Ratio	f = 120 Hz, Output Referred				
	V <sub>S</sub> = 20V, V <sub>RIPPLE</sub> = 1 Vrms	-50	-65		dB
	$V_{S} = 7V, V_{RIPPLE} = 0.5 Vrms$		-40		dB
Noise	Equivalent Input Noise				
	$R_{S} = 0, C_{IN} = 0.1 \ \mu F,$		2.5		μV
	BW = 20 Hz–20 kHz, Output Noise Wideband				
	$R_{S} = 0, C_{N} = 0.1 \ \mu F, A_{V} 200$		0.80		mV
Open Loop Gain	$R_{S} = 0, f = 100 \text{ kHz}, R_{L} = 8\Omega$		70		dB
Input Offset Voltage			15		mV
Input Bias Current			50		nA
Input Impedance	Open Loop		4		MΩ
DC Output Level	V <sub>S</sub> = 20V	9	10	11	V
Slew Rate			2.0		V/µs
Power Bandwidth			65		kHz
Current Limit			1.0		А

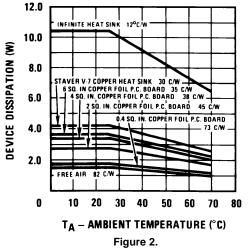
(1) For operation at ambient temperature greater than 25°C, the LM1877 must be derated based on a maximum 150°C junction temperature.

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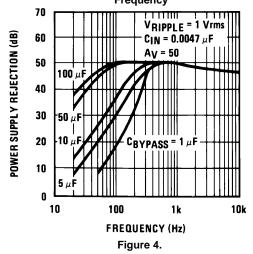
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### **Typical Performance Characteristics**

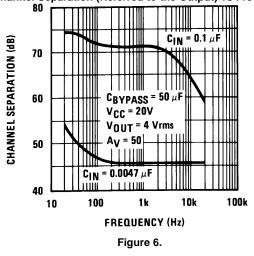




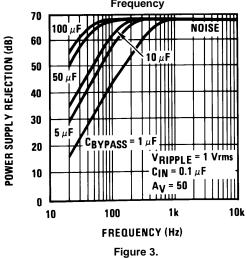




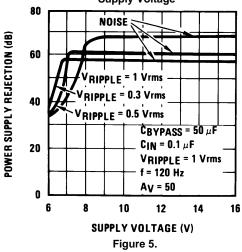
Channel Separation (Referred to the Output) vs Frequency



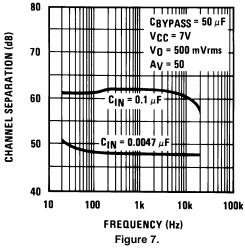
Power Supply Rejection Ratio (Referred to the Output) vs Frequency



Power Supply Rejection Ratio (Referred to the Output) vs Supply Voltage



Channel Separation (Referred to the Output) vs Frequency





0.1

0.01

100

80

60

40

20

0

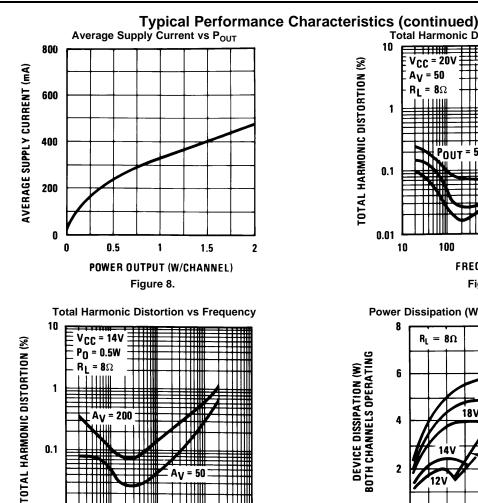
100

**VOLTAGE GAIN (dB)** 

10

100

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 $A_V = 50$ 

10k

100k

1M

V<sub>S</sub> = 20V  $R_L = 8\Omega$ 

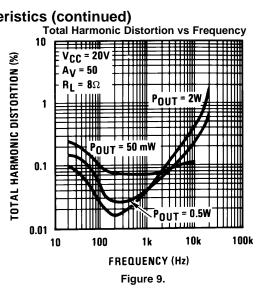
100k

1k

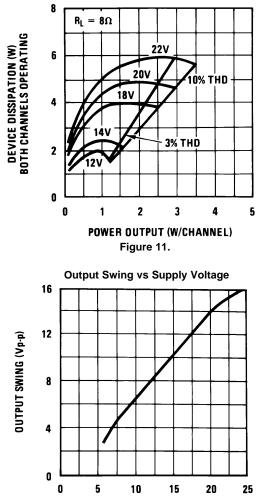
**FREQUENCY** (Hz)

Figure 10.

**Open Loop Gain vs Frequency** 



Power Dissipation (W) Both Channels Operating





1k

10k

**FREQUENCY** (Hz) Figure 12.

SUPPLY VOLTAGE (V)

Figure 13.



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**Typical Applications** 

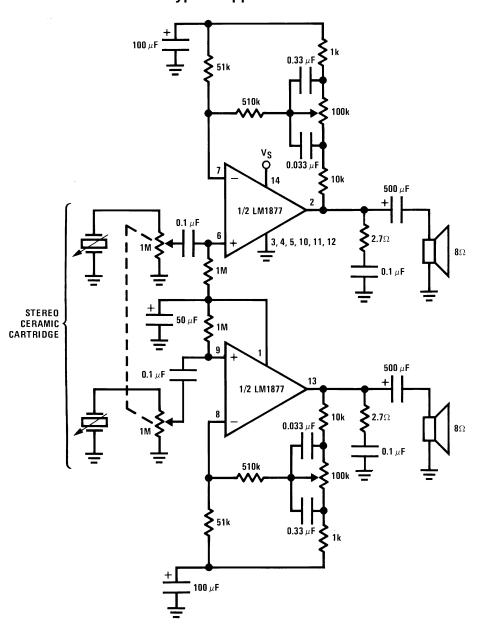
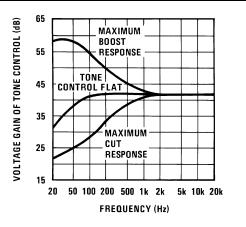


Figure 14. Stereo Phonograph Amplifier with Bass Tone Control





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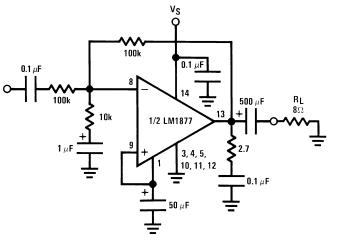




Figure 16. Inverting Unity Gain Amplifier

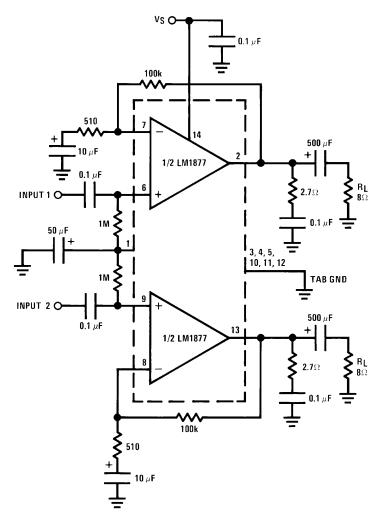
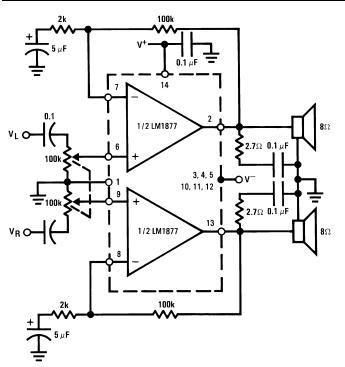


Figure 17. Stereo Amplifier with  $A_V = 200$ 





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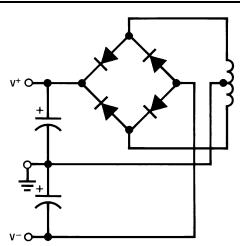


Figure 18. Non-Inverting Amplifier Using Split Supply

Figure 19. Typical Split Supply

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Changes	from Revision	Δ (April 20	13) to Revision B	
onanges				

•	Changed layout of National Data Sheet to TI format	7
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10-Dec-2020

# PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LM1877MX-9/NOPB	ACTIVE	SOIC	NPA	14	1000	RoHS & Green	(6) SN	Level-3-260C-168 HR	0 to 70	LM1877M -9	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND**: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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# PACKAGE MATERIALS INFORMATION

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## TAPE AND REEL INFORMATION





## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal
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Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM1877MX-9/NOPB	SOIC	NPA	14	1000	330.0	16.4	10.9	9.5	3.2	12.0	16.0	Q1

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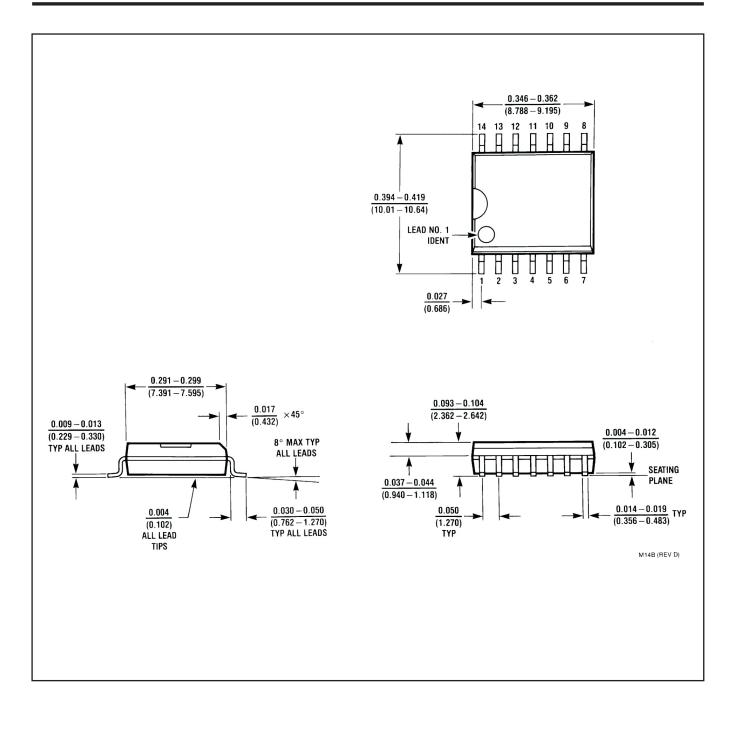
# PACKAGE MATERIALS INFORMATION

8-Apr-2013



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM1877MX-9/NOPB	SOIC	NPA	14	1000	367.0	367.0	38.0





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